NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE82H140 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

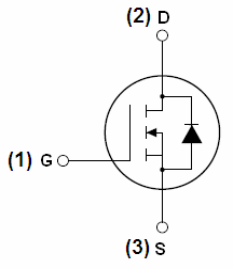
- V_{DS} = 82V,I_D =140A
  $R_{DS(ON)}$ < 5.2mΩ @ V_{GS}=10V (Typ:4.3mΩ)
- Special process technology for high ESD capability
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

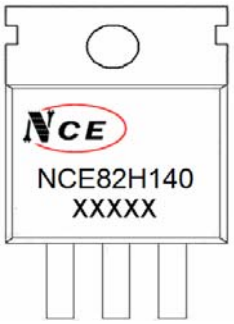
- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment

TO-220-3L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE82H140	NCE82H140	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	82	V
Gate-Source Voltage	V_{GS}	±20	V
Drain Current-Continuous	I_D	140	A
Drain Current-Continuous(T_C=100℃)	I_D (100℃)	99	A
Pulsed Drain Current	I_{DM}	480	A
Maximum Power Dissipation	P_D	220	W
Derating factor		1.47	W/℃
Single pulse avalanche energy (Note 5)	E_{AS}	1500	mJ
Operating Junction and Storage Temperature Range	T_J,T_{STG}	-55 To 175	℃

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Thermal Characteristic

Thermal Resistance,Junction-to-Case (Note 2)	$R_{\theta Jc}$	0.68	℃/W

Electrical Characteristics (T_C=25℃unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V I_D=250μA	82	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=82V,V_{GS}=0V	-	-	1	μA
Gate-Body Leakage Current	I_{GSS}	V_{GS}=±20V,V_{DS}=0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS},I_D=250μA	2	3	4	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	V_{GS}=10V, I_D=20A	-	4.3	5.2	mΩ
Forward Transconductance	g_{FS}	V_{DS}=5V,I_D=20A	65	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C_{lss}	V_{DS}=40V,V_{GS}=0V, F=1.0MHz	-	7900	-	PF
Output Capacitance	C_{oss}		-	445	-	PF
Reverse Transfer Capacitance	C_{rss}		-	384	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	$t_{d(on)}$	V_{DD}=30V, R_L=1Ω V_{GS}=10V,R_{GEN}=2.5Ω	-	23	-	nS
Turn-on Rise Time	t_r		-	42	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	75	-	nS
Turn-Off Fall Time	t_f		-	26	-	nS
Total Gate Charge	Q_g	V_{DS}=40V,I_D=20A, V_{GS}=10V	-	158	-	nC
Gate-Source Charge	Q_{gs}		-	32	-	nC
Gate-Drain Charge	Q_{gd}		-	51	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V_{SD}	V_{GS}=0V,I_S=140A	-	-	1.2	V
Diode Forward Current (Note 2)	I_S	-	-	-	140	A
Reverse Recovery Time	t_{rr}	TJ = 25°C, IF = 20A di/dt = 100A/μs (Note3)	-	50	-	nS
Reverse Recovery Charge	Qrr		-	110	-	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t ≤ 10 sec.
3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
4. Guaranteed by design, not subject to production
5. EAS condition：Tj=25℃,VDD=40V,VG=10V,L=0.5mH,Rg=25Ω

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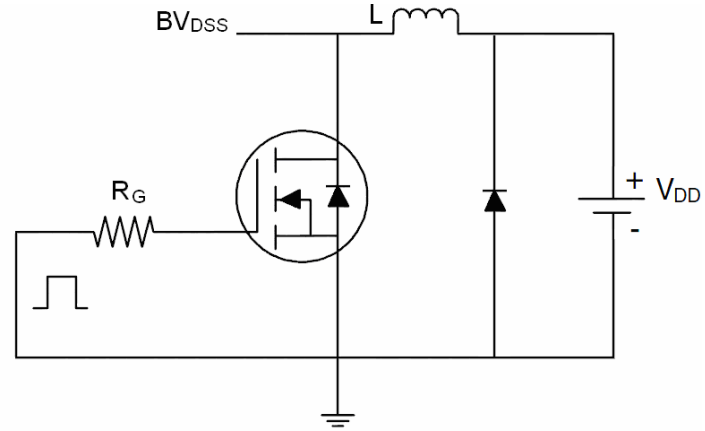
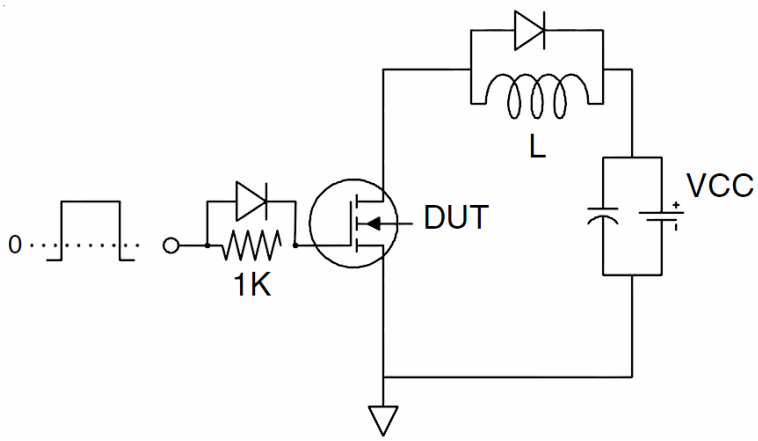
Test circuit

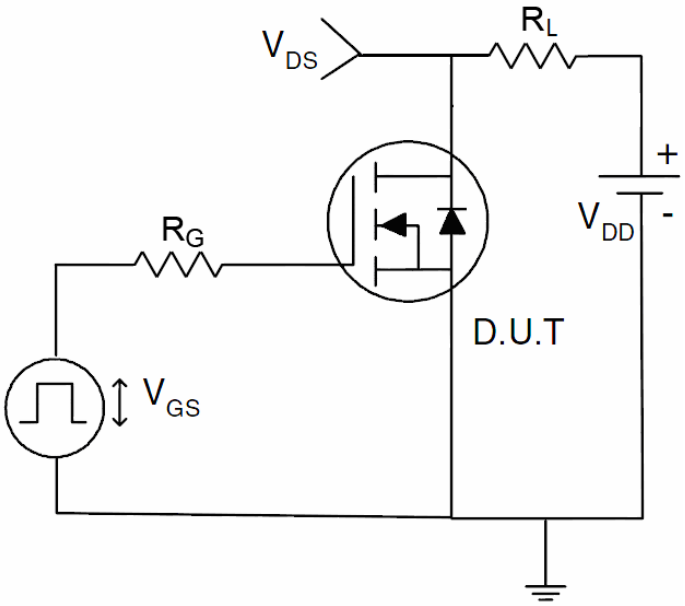
1）E_{AS} test Circuit



2）Gate charge test Circuit



3）Switch Time Test Circuit



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Typical Electrical and Thermal Characteristics (Curves)

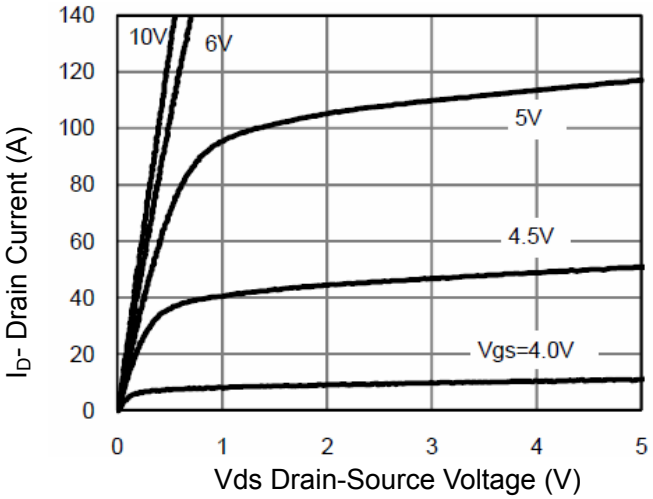

Figure 1 Output Characteristics

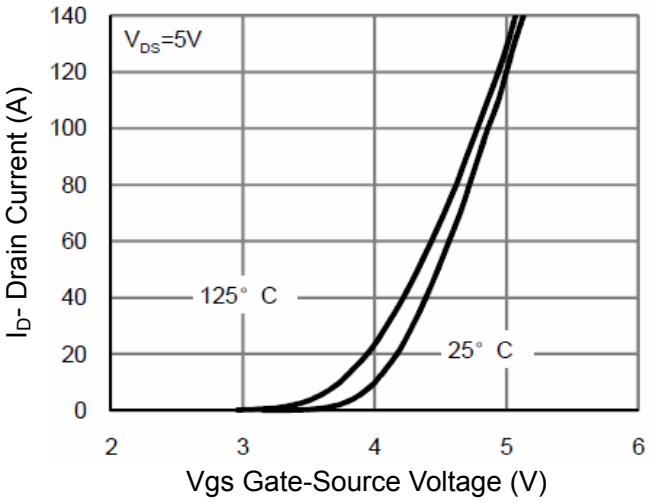

Figure 2 Transfer Characteristics

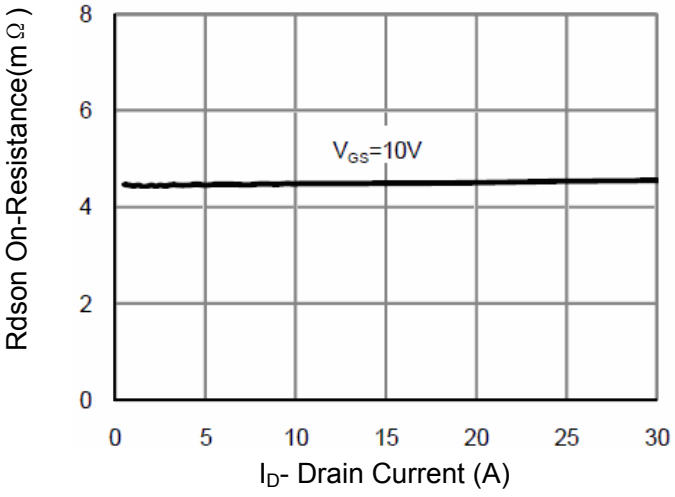

Figure 3 Rdson- Drain Current

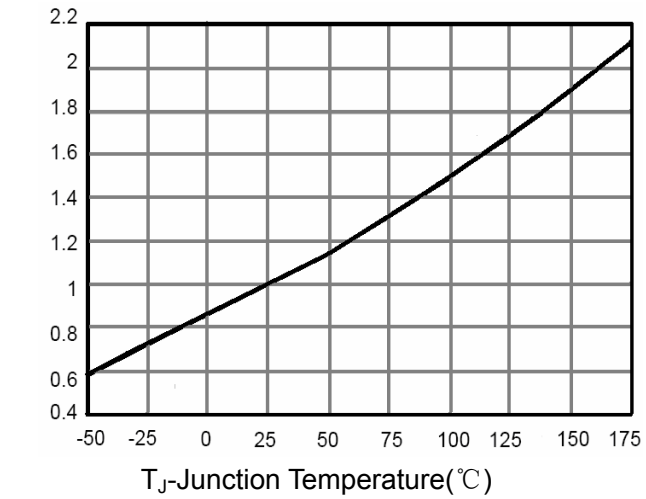

Figure 4 Rdson-JunctionTemperature

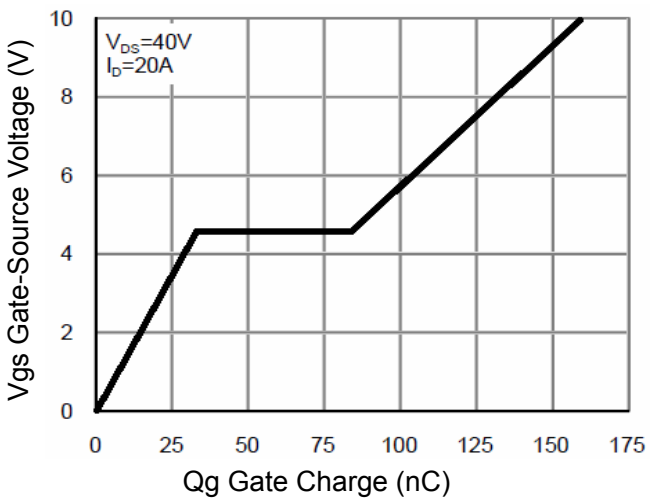

Figure 5 Gate Charge

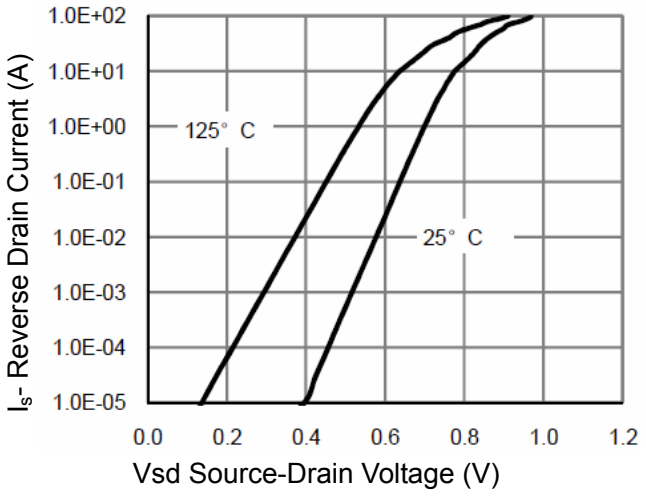

Figure 6 Source- Drain Diode Forward

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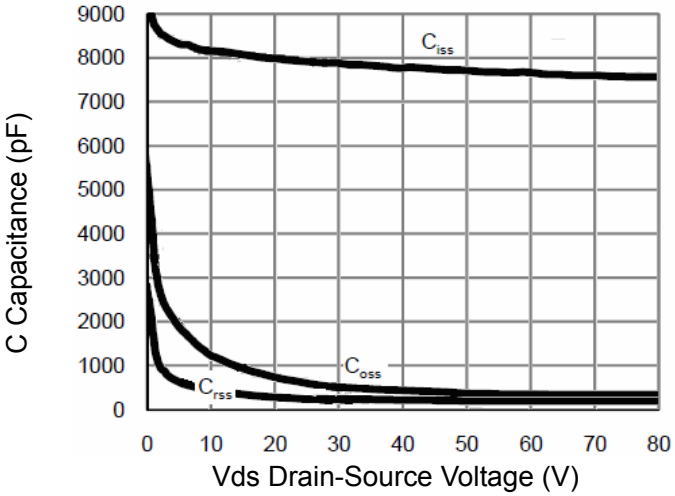

Figure 7 Capacitance vs Vds

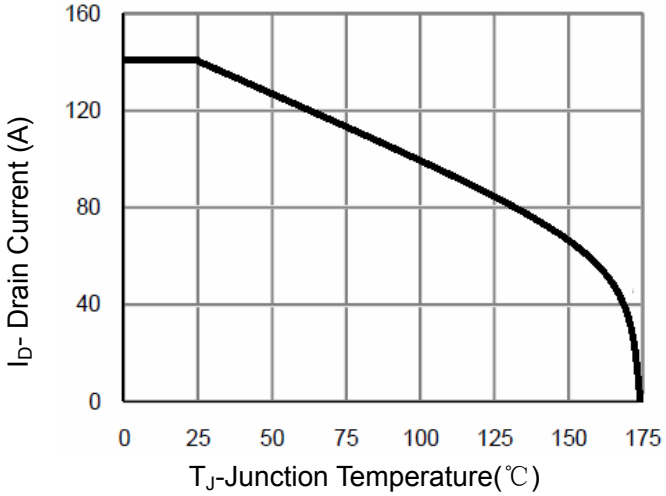

Figure 9 Current De-rating

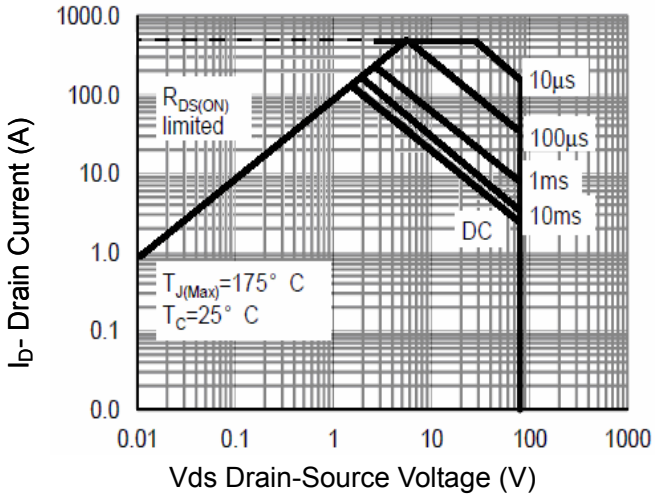

Figure 8 Safe Operation Area

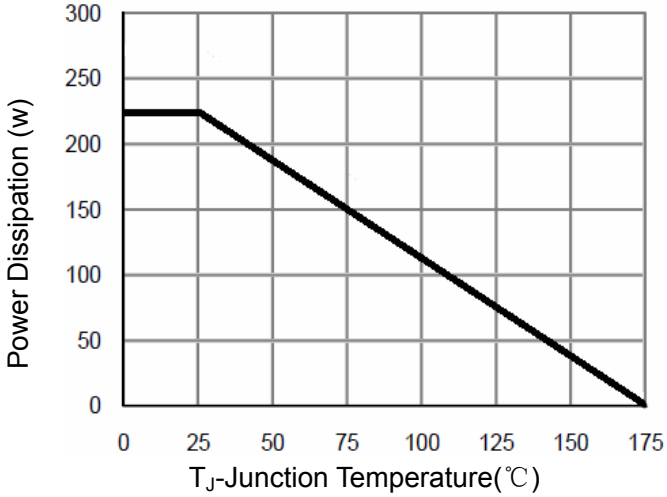

Figure 10 Power De-rating

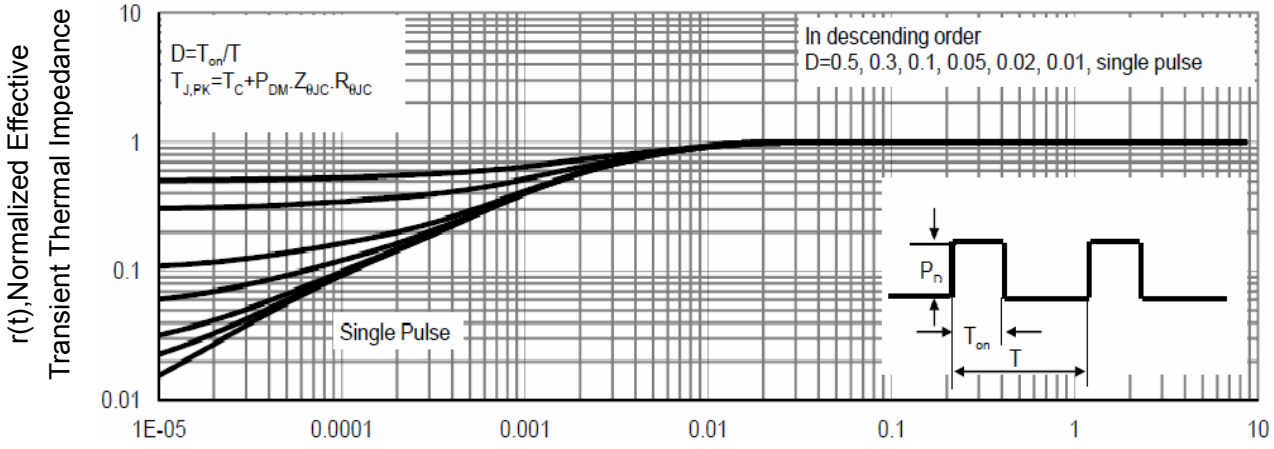

Figure 11 Normalized Maximum Transient Thermal Impedance

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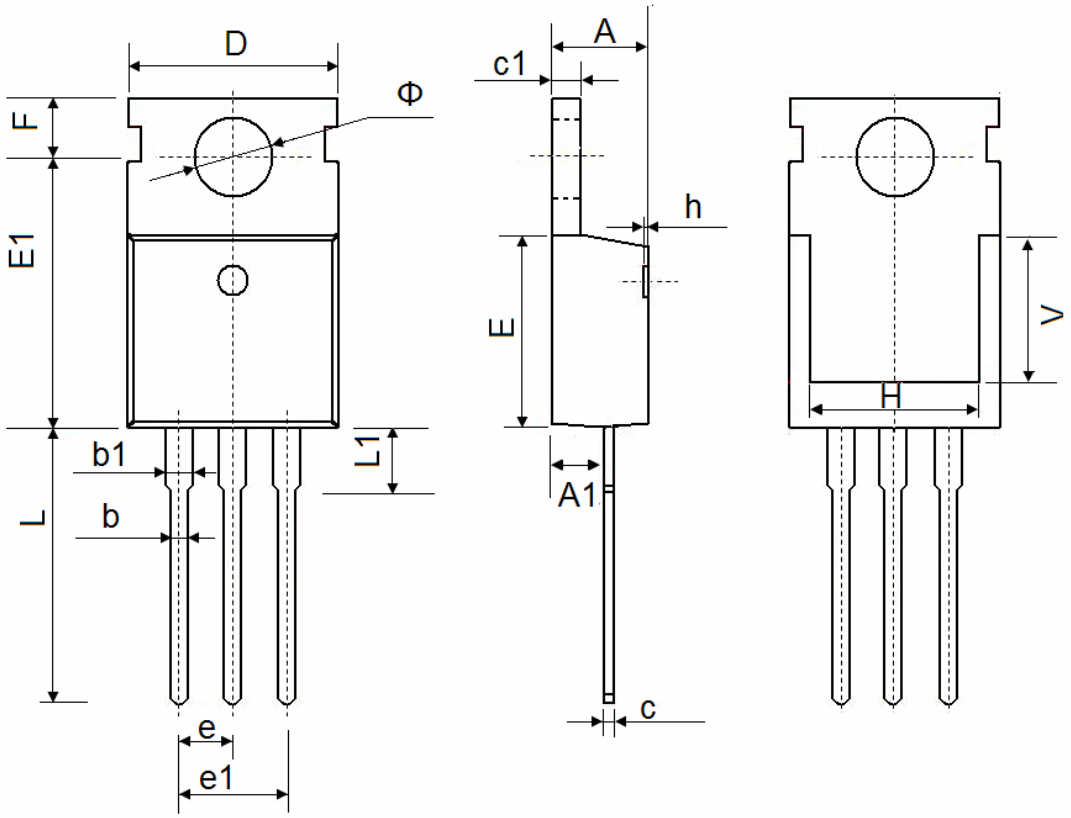
TO-220-3L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.400	4.600	0.173	0.181
A1	2.250	2.550	0.089	0.100
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.330	0.650	0.013	0.026
c1	1.200	1.400	0.047	0.055
D	9.910	10.250	0.390	0.404
E	8.9500	9.750	0.352	0.384
E1	12.650	12.950	0.498	0.510
e	2.540 TYP.		0.100 TYP.	
e1	4.980	5.180	0.196	0.204
F	2.650	2.950	0.104	0.116
H	7.900	8.100	0.311	0.319
h	0.000	0.300	0.000	0.012
L	12.900	13.400	0.508	0.528
L1	2.850	3.250	0.112	0.128
V	7.500 REF.		0.295 REF.	
Φ	3.400	3.800	0.134	0.150

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